TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8403K

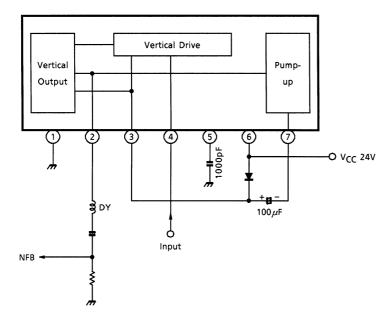
POWER AMPLIFIER FOR DRIVING A DEFLECTION CIRCUIT OF A COLOR TELEVISION

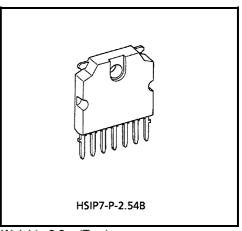
TA8403K is a power amplifier for driving a vertical deflection circuit of a small and medium screen size color television. TA8403K is available for constructing a stable deflection circuit with small number parts in an application with a single chip signal processing IC TA8879N.

FEATURES

- Large output current : 1.8Ap-p (Max.)
- Small power dissipation with a pump-up circuit
- Small number external parts

BLOCK DIAGRAM





Weight : 2.2 g (Typ.)

TERMINAL NAME

- 1. GND
- 2. Vertical Output
- 3. Pump-up Power Supply
- 4. Input
- 5. Phase Compensation
- 6. Power Supply
- 7. Pump-up Output

000707EBA1

TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or

- to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
 The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

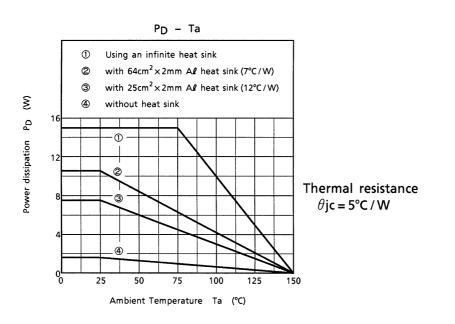
The products described in this document are subject to the foreign exchange and foreign trade laws.
The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others

The information contained herein is subject to change without notice.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Power Supply Voltage	VCC	30	V	
Pump-up Power Supply Voltage	Vvt	60	V	
Terminal Voltage	Ein	E _{in} GND -0.3 ~ VVt +0.3		
Input Signal Voltage	e _{in}	0~1.2	V	
Power Dissipation	PD	15 (Note)	W	
Operating Temperature	Topr	-20~85	°C	
Storage Temperature	T _{stg}	-55~150	°C	

Note: Using an infinite heat sink



RECOMMENDED OPERATING CONDITION

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Power Supply	V _{CC}	_	24	27	V
Deflection Output Current	I _{2p-p}		_	1.8	A _{p-p}

TOSHIBA

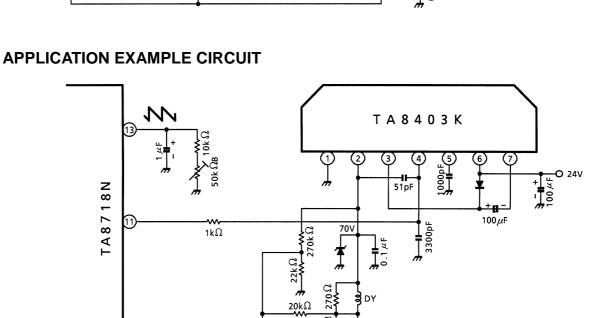
ELECTRICAL CHARACTERISTICS (Ta = 25°C, V_{CC} = 24V)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Saturation Voltage of the Vertical Output Transistor (1)	V _{v (sat) 1}	1	Note 1:	0.3	0.5	1.0	V
Saturation Voltage of the Vertical Output Transistor (2)	V _{v (sat) 2}	1	Note 2:	1.0	1.8	3.6	V
Saturation Voltage of the Pump-up Output Transistor (1)	V _{p (sat)} 1	1	Note 3:	1.0	2.0	3.0	V
Saturation Voltage of the Pump-up Output Transistor (2)	V _{p (sat)} 2	1	Note 4:	0.3	0.8	1.6	V
Output Current with no input	۱ _b	1	1 Note 5:	10.0	15.0	30.0	mA
Center Output Voltage	V _{center}			10.0	12.0	14.0	V

Note 1: $SW_1 : ON, SW_2 : C, SW_3 : ON, SW_4 : B, SW_5 : A, SW_6 : A$ Measure the voltage of pin2.

- Note 2: SW_1 : ON, SW_2 : C, SW_3 : ON, SW_4 : A, SW_5 : A, SW_6 : B Measure the voltage of pin2, V_2 . V_V (sat) $_2$ = V_{CC} – V_2
- Note 3: SW_1 : ON, SW_2 : B, SW_3 : OFF, SW_4 : A, SW_5 : C, SW_6 : A Measure the voltage of pin7, V_7 . V_P (sat) 1 = V_{CC} – V_7
- Note 4: SW_1 : OFF, SW_2 : C, SW_3 : OFF, SW_4 : A, SW_5 : B, SW_6 : B Measure the voltage of pin7.
- Note 5: $SW_1 : ON, SW_2 : A, SW_3 : ON, SW_4 : C, SW_5 : A, SW_6 : B$ Measure the sink current into pin3. Measure the voltage of pin2.
- Note 6: TA8403K is checked its output wave form in a real operating circuit.

2001-02-07 4/5



N

14

1kΩ

1000F

2.2kD 3300 µF

+**β** 1μF

DY 20.

12.2 2.2

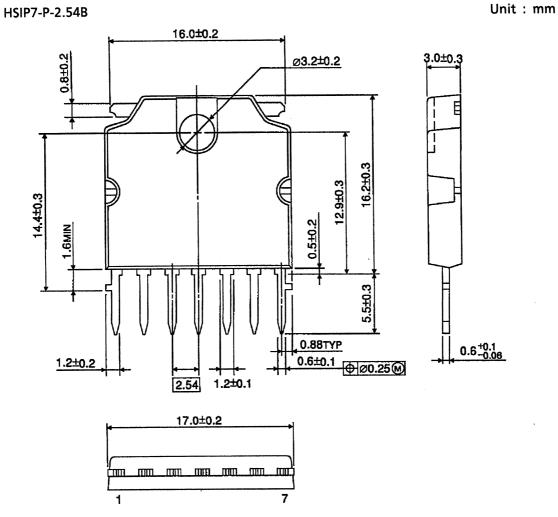
T A 8 4 0 3 K Ţ 7 3 (4 6 0.01 µF 0.01 µF 0.01 // F т 1000рF ٦ SW3 SW SW4 34Ω/ 15W ^B 9 _____0 ∩ вŶ sw₂ P c, В 34Ω/ 15W .2kΩ g Α sw₆ ↓ 1.4V В **∳** 26∨ ► 24V 470pF -11-68kΩ 1kΩ R : 1/4W C : 50V 12V **μ-π**+ 1μF + ■ 1 | | | | 11V**7** 0.022μF ZOKD 1000F Ğ₹ 6.8k Ω

TEST CIRCUIT 1

TOSHIBA

TOSHIBA

PACKAGE DIMENSIONS



Weight: 2.2 g (Typ.)